



M T B F

(E I A J R C R - 9 1 0 2)

Model	MGW100512
-------	-----------

No.	P a r t s		Q'ty of Device	Failure rate [10 ⁻⁶ /H]	R e f e r e n c e
1	I C	Monolithic	3	0.0720	
2		Hybrid	0	0.0000	
3	Transistors		3	0.1012	
4	Diodes		7	0.1390	
5	LED•Optocouplers		1	0.0700	
6	Resistors		25	0.3248	
7	Capacitors		25	0.1850	
8	Transformer•Choke Coil		3	0.0690	
9	Connectors		187	0.0255	
10	Others		2	0.2200	
Total Failure Rate [10 ⁻⁶ /H]				1.2065	

M T B F	[H]	829,000
Ambient Temperature	[°C]	—
Load Factor	[%]	—